TECHNICAL DATA DATA SHEET 4514, REV. A

POWER SCHOTTKY RECTIFIER Low Reverse Leakage

Applications:

• Switching Power Supply • Converters • Free-Wheeling Diodes • Polarity Protection Diode

Features:

- Ultra Low Reverse Leakage Current
- Soft Reverse Recovery at Low and High Temperature
- Low Forward Voltage Drop
- Low Power Loss, High Efficiency
- High Surge Capacity
- Guard Ring for Enhanced Durability and Long Term Reliability
- Guaranteed Reverse Avalanche Characteristics

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	V_{RWM}	-	15	V
Max. Average Forward	I _{F(AV)}	50% duty cycle, rectangular	30	Α
Current		wave form		
Max. Peak One Cycle Non-	I _{FSM}	8.3 ms, half Sine wave	570	Α
Repetitive Surge Current		(per leg)		
Non-Repetitive Avalanche	E _{AS}	$T_J = 25 ^{\circ}\text{C}, I_{AS} = 1.3 \text{A},$	27	mJ
Energy		L = 40mH (per leg)		
Repetitive Avalanche	I _{AR}	I _{AS} decay linearly to 0 in 1 μs	1.3	Α
Current		f limited by T _J max V _A =1.5V _R		
Thermal Resistance	R_{thJC}	Per Package	0.9	°C/W
Max. Junction Temperature	Τ _J	-	-65 to +175	°C
Max. Storage Temperature	T _{stg}	-	-65 to +175	°C

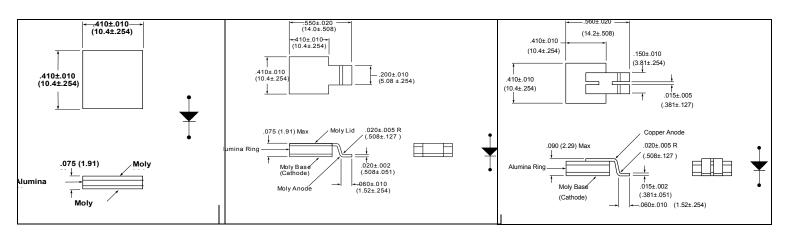
Electrical Characteristics:

Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage Drop	V_{F1}	@ 30A, Pulse, T _J = 25 °C	0.37	V
		(per leg) measured at the leads		
	V_{F2}	@ 30A, Pulse, T _J = 125 °C	0.33	V
		(per leg) measured at the leads		
Max. Reverse Current	I _{R1}	@V _R = 15V, Pulse,	14	mA
		$T_J = 25 ^{\circ}\text{C} \text{ (per leg)}$		
	I _{R2}	@V _R = 15V, Pulse,	680	mA
		T_J = 125 °C (per leg)		
Max. Junction Capacitance	C _T	@V _R = 5 V, T _C = 25 °C	2400	pF
		f _{SIG} = 1 MHz,		
		V_{SIG} = 50mV (p-p) (per leg)		

Due to the nature of the 15V Schottky devices, some degradation in t_{rr} performance at high temperatures should be expected, unlike conventional lower voltage Schottkys.

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Mechanical Dimensions: in inches / mm



SHD-3A SHD-3B

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